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Well-Oriented TIPS Pentacene Crystal Growth

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Status:

Seeking R&D and/or licensing partner

Patent Pending

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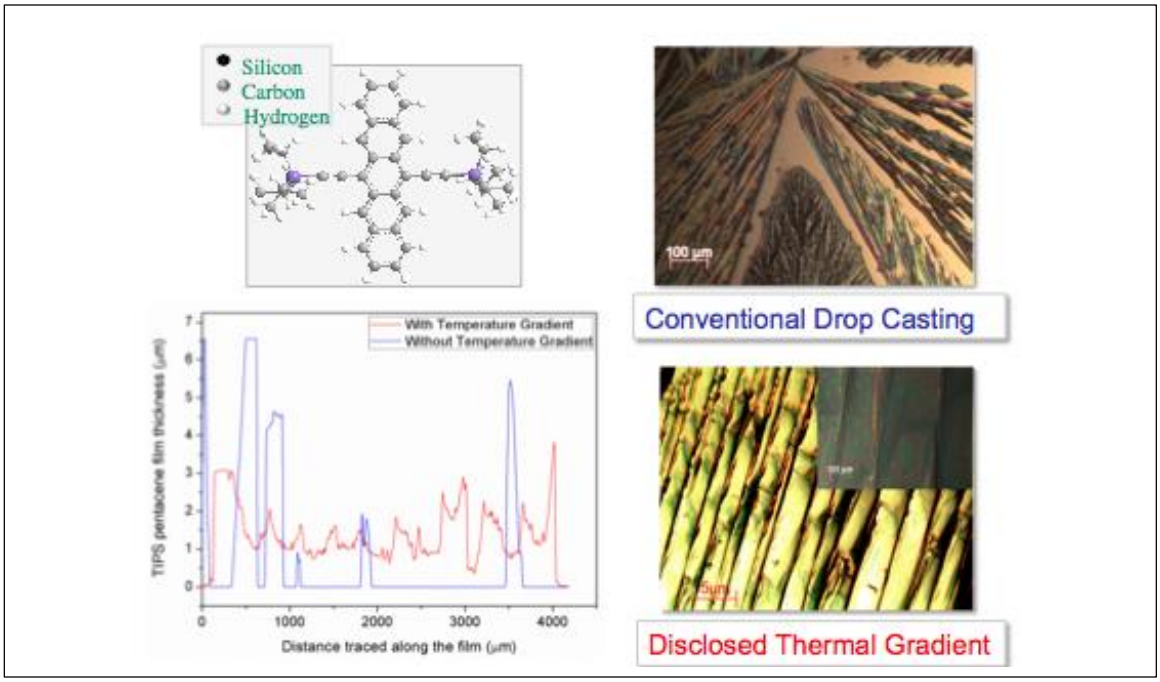
Crystal Growth via Temperature Gradient

- Novel method for improved growth of 6,13-bis(triisopropylsilylethynyl)-pentacene (TIPS pentacene) films from solution
- Controlled rate of solvent evaporation via low to high temperature gradient
- Results in controlled growth of TIPS pentacene on substrate

Advantages

- Method produces smooth adjacent crystals with good uniformity and surface continuity not possible with drop or spun cast TIPS pentacene
- Testing of films shows 10X improvement in mobility (0.004 cm^2/V s for non-annealed films vs 0.05 cm^2/Vs for our technology)



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